

# CBM-90-IRD-X33-850nm

# **Mosaic Array Series**

# **Infrared Chip On Board LEDs**



### Features

- Mosaic Array Infrared LED chipset with surface emitting area of 9  $\rm mm^2$
- Vertical chip LED technology for high power density and uniform emission
- High thermal conductivity copper coreboard package
- Can be operated at variable drive currents up to 18A

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# **Applications**

- Medical and Scientific Instrumentation
- Fiber-coupled illumination
- Inspection
- Machine Vision



### **Technology Overview**

Luminus CBM-90-IRD-X33 LEDs benefit from innovations in device technology, chip packaging and thermal management. This suite of technologies give engineers and system designers the freedom to develop solutions both high in power and efficiency.

#### Reliability

Luminus CBM-90-IRD-X33 LEDs have passed a rigorous suite of environmental and mechanical stress tests, including mechanical shock, vibration, temperature cycling and humidity. They are fully qualified for use in a wide range of high performance and high efficacy applications.

#### **REACh & RoHS Compliance**

The Luminus CBM-90-IRD-X33 LED is compliant to the Restriction of Hazardous Substances Directive or RoHS. The restricted materials including lead, mercury cadmium hexavalent chromium, polybrominated biphenyls (PBB) and polybrominated diphenyl ether (PBDE) are not used.

### **Understanding Luminus CBM-90-IRD-X33 LED Test Specifications**

Every Luminus LED is fully tested to ensure it meets the high quality standards customers have come to expect from Luminus products.

#### **Testing Temperature**

Luminus CBM-90-IRD-X33 LEDs are tested and binned at 40°C heatsink temperature. Temperature curves are provided to allow users to scale the data for actual operating temperature conditions.



### **CBM-90-IRD Binning Structure**

All CBM-90-IRD LEDs are tested for radiometric power / peak wavelength and placed into one of the following flux / wavelength bins.

#### Flux Bins<sup>1</sup>

Bin Code	Radiometric Power at 13.5A, t <sub>p</sub> =20ms		
Bin Code	Minimum Flux (W)	Maximum Flux (W)	
К	11	12.1	
L	12.1	13.31	
М	13.31	14.64	
N	14.64	16.11	
Р	16.11	17.72	

Note 1: Luminus maintains a +/-6% tolerance in flux measurements.

#### **Wavelength Bins**

Bin Code	Minimum Peak Wavelength (nm)	Maximum Peak Wavelength (nm)
840	840	845
845	845	850
850	850	855
855	855	860
860	860	865
865	865	870



### **Product Ordering and Shipping Part Number Nomenclature**

All CBM-90-IRD-X33 products are packaged and labeled with part numbers as outlined in below. When shipped, each tray will contain only a single flux wavelength and Vf bin. The part number designation is as follows:

Products	Ordering Part Number	Description
CBM-90-IRD-X33	CBM-90-IRD-X33-F###	CBM-90-IRD Array chipset consisting of 9x1mm2 dual junction Infrared LEDs, a thermistor, connectors, and a square copper-core PCB.

CBM — 90 — IRD — X33 — F###

Product Family	Chip Area	Color	Package Configuration	Bin Kit <sup>1,2</sup>
CBM: Copper- core PCB, Multi Chip Array, No Encapsulation	90: 9 mm²	IRD = Dual junction Infrared	X33: 28 mm x 26.75 mm - Common Anode Package See Mechanical Drawing section	See below for flux and wavelength binning informa- tion

Typ. Centroid	Minimum Flux Bin	Lens Angle	Ordering
Wavelength (nm)	(W)		Part Number
850	К	120 (lambertian)	CBM-90-IRD-X33-K850



# **Optical and Electrical Characteristics**

**Optical and Electrical Characteristics<sup>1</sup>** 

Parameter	Symbol	Package Type	Unit
		X33-850	
Forward Current	I <sub>f</sub>	13.5	A
Output Power Typical	PO	13	W
Minimum Forward Voltage <sup>1</sup>	V <sub>f min</sub>	3.0	V
Forward Voltage Typical	V <sub>f</sub>	3.6	V
Maximum Forward Voltage <sup>1</sup>	V <sub>f max</sub>	4.0	V
Viewing Angle	2Ø <sub>1/2</sub>	120	deg
Peak Wavelength Typical	$\lambda_{P}$	855	nm
Centroid Wavelength Typical	λ	850	nm
FWHM Typical	Δλ <sub>1/2</sub>	35	nm
Temperature Coefficient of Foward voltage	TC <sub>vf</sub>	-2	mV/°C
Temperature Coefficient of Radiometric Power	TC <sub>PO</sub>	-0.3	%/°C
Temperature Coefficient of Wavelength	<b>ΤC</b> <sub>λ</sub>	0.2	nm/°C
Thermal Resistance (Electrical)	R <sub>th (i-b)</sub>	0.5	°C/W
Emitting Area		10.24	mm <sup>2</sup>
Emitting Area Dimensions		3.2 x 3.2	mm <sup>2</sup>

Note 1: Parts are tested and binned at a current of 13.5A, 20ms single pulse and a constant heatsink temperature of  $T_{hs} = 40$  °C.



# **Optical and Electrical Characteristics**

#### **Absolute Ratings**<sup>2,5</sup>

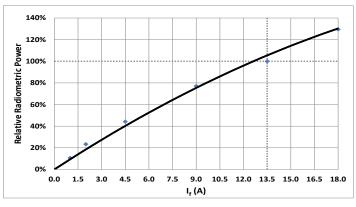
Parameter	Symbol	Rating	Unit
Absolute Minimum Current (CW or pulse) <sup>3,4</sup>		0.2	А
Absolute Maximum Current (CW) <sup>3,4</sup>		18.0	А
Reverse Voltage	VR	5	V
Storage Temperature	Тѕтд	-40~100	°C
Maximum Junction Temperature <sup>3,4</sup>	T	115 ℃	°C

Note 2: To prevent damage refer to operating conditions and derating curves for appropriate maximum operating conditions

- Note 3: Luminus CBM-90-IRD-X33 LEDs *ar*e designed for operation up to an absolute maximum forward drive current as specified above. Product lifetime data is specified at typical forward drive currents. Sustained operation at absolute maximum currents will result in a reduction of device lifetime compared to typical forward drive currents. Actual device lifetimes will also depend on junction temperature.
- Note 4: Maximum operating case temperature combined with maximum drive current defines the total maximum operating condition for the device. To prevent damage, please operate devices within specified conditions.
- Note 5: Caution must be taken not to stare at the light emitted from these LEDs. Under special circumstances, the high intensity could damage the eye.

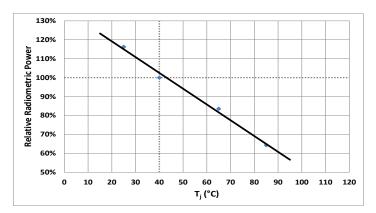


## **Optical and Electrical Characteristics**

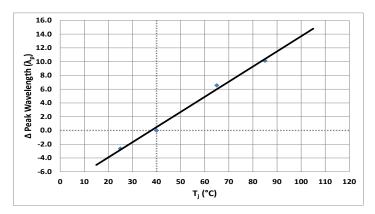


**Relative Output Flux vs. Forward Current** 

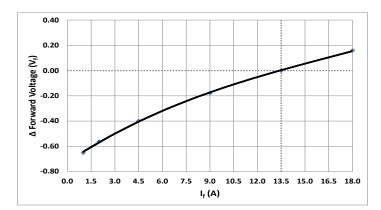
#### **Relative Radiometric Power vs. Temperature**



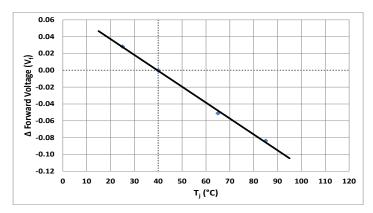
**Relative Peak Wavelength vs. Temperature** 



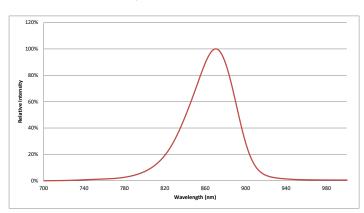
#### **Relative Voltage vs. Forward Current**



#### **Relative Voltage vs. Temperature**



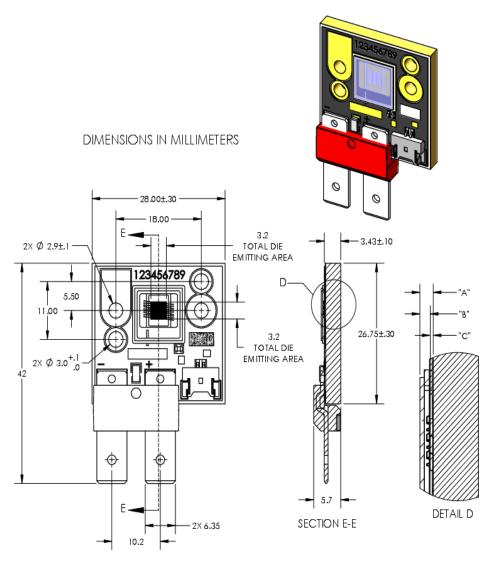
#### **Typical Spectrum**



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## **Mechanical Dimensions**



DIMENSION	DESCRIPTION	NOMINAL DIMENSION	TOLERANCE
"A"	TOP OF METAL SUBSTRATE TO TOP OF WINDOW	.93	±.13
"B"	TOP OF DIE EMITTING AREA TO TOP OF WINDOW	.73	±.13
"C"	TOP OF METAL SUBSTRATE TO TOP OF DIE EMITTING AREA	.21	±.02

DWG-002978 REV01

Recommended connector for Anode and Cathode:

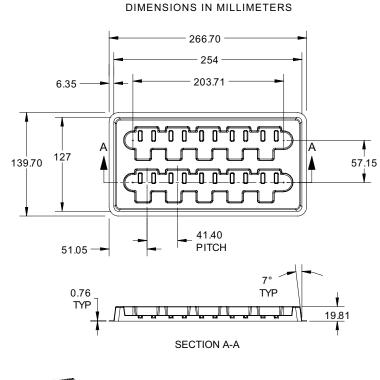
Panduit Disco Lok<sup>™</sup> Series P/N: DNF14-250FIB-C or JST Manufacturing Co: SPS-61T-250 for AWG 16 to 14. Panduit Disco Lok<sup>™</sup> Series P/N: DNF10-250FIB-L or JST Manufacturing Co: SPS-91T-250 for AWG 12 to 10. (Check NEC standards for ampacity of the power cable being used.)

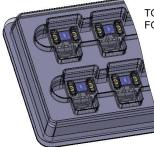
Thermistor Connector: GCT P/N WTB08-021S-F.

Recommended Female: MOLEX P/N 51146-0200 (Not recommended for new designs), GCT P/N WTB06-020H-A or equivalent.

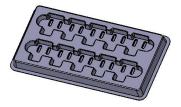


# **Shipping Tray Outline**





TOP TRAY SHOWN TRANSPARENT FOR REFERENCE ONLY





# Packing and Shipping Specification (CBM-90-IRD)

#### **Packing Specification**

Packing Configuration	Qty /Pack	Reel Dimensions (diameter x W, mm)	Gross Weight (kg)
Stack of 5 trays with 10 devices per tray Each pack is enclosed in ESD bag	50	150 x 280 x 85	2.7

#### **Product Label Specification**

#### Label Fields (subject to change):

- 6-8 digit Box number (for Luminus internal use)
- Luminus ordering part number
- Quantity of devices in pack
- Part number revision (for Luminus internal use)
- Customer's part number (optional)
- Bin (FF-WW) as defined page 3
- 2D Bar code



### **Shipping Box**

		te Filament™	
BT-012345	Qty: 50		nd attach
PT-120-G-L11-MPG	Rev 01		l off label a
12345678			for traceability peel off label and attach
5F			for trace
	RoHS C	ompliar	nt

Sample label – for illustration only

Shipping Box	Quantity	Material	Dimensions (L x W x H, mm)
Carton Box	1 -20 packs (50 - 1000 Devices)	S4651	560 x 560 x 200





## **History of Changes**

Rev	Date	Description of Change
Α	08/22/2019	Preliminary Release
01	03/04/2020	Initial Release to Production Updated thermal coefficient of radiometric power and typical FWHM on page 5 Updated graphs on page 7 Updated mechanical drawing on page 8
02	08/04/2020	Updated product picture on front page Updated temperature coefficient of radiometric power and thermal resistance on page 5 Updated mechanical drawing on page 8

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